

Model No. VCC-94A2WH

Features:

- 940nm VCSEL chip
- Typical 2W peak pulse output at 2.5A
- High PCE (Power Conversion Efficiency): 41%
- -20 to 85 °C operating temperature
- Chip size: $1260 \times 1113.6 \pm 15 \mu m$
- Electrode Side: Gold alloy on both anode P (emission side) and cathode N (backside)

Applications:

- Sensing light source
- Optical encoders
- Photoelectric sensors
- 3D sensing
- 3D imaging including Time of Flight, Structure light, Iris/ Facial recognition etc.

Absolute Maximum Ratings (TA = 25°C unless otherwise noted)

Parameter	Symbol	Rating
Storage Temperature	Tstg	-40 to 85 °C
Operating Temperature	Тор	-20 to 85 °C
Continuous Forward Current	lf	2.6A
Maximum package SMT solder reflow Temperature		260°C, 10 seconds

Note: The maximum CW laser current in the Absolute Maximum Ratings is valid for the operating temperature noted at the table above. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.

Electro-Optics Characteristics (Ta=25°C unless otherwise noted)

Parameters	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Threshold Current	Ith	-	500	-	mA	
Slope Efficiency	η	0.9	1.0	-	W/A	lf = 2500mA
Optical Output Power	P₀		2000	-	mW	lf = 2500mA
Center Wavelength	λc	930	940	950	nm	lf = 2500mA
Beam Divergence	Θ		26		degree	Full Width 1/e ²
Operating Voltage	Vf	1.7	2.0	2.3	V	lf = 2500mA
Power Conversion Efficiency	PCE		41		%	lf = 2500mA
Wavelength Shift	$\Delta\lambda/\Delta T$	-	0.07	-	nm/°C	lf = 2500mA

Note 1: Forward Voltage (V_f) measurement allowance is ±0.1V.

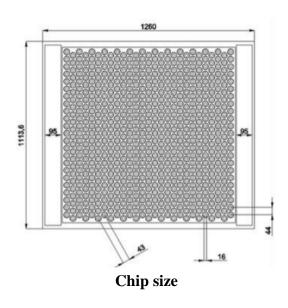
Note 2: Center Wavelength (λ_c) measurement allowance is ±1.5nm.

Note 3: Others measurement allowance is ±10%.

Note 4: Test DUTs are mounted on star board and measured with operating bias current @ 2.5A, Duty Cycle:1%.

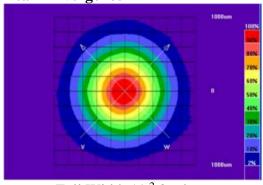
Note: The specifications are subject to change without notice.

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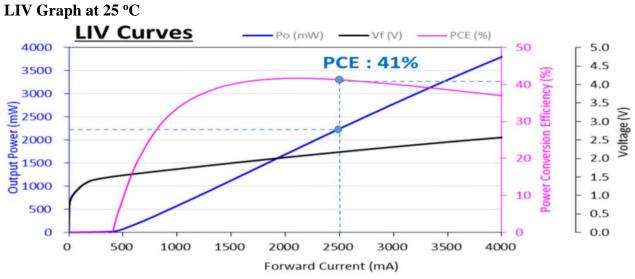




Typical Performance Graph: Beam Divergence

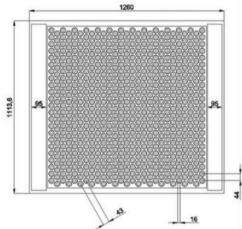


Full Width 1/e² 26 degree



Note: Curves measurement at 0 ~ 4A current sweep with 1% duty cycle.

Dimensions (unit: µm):



Specification	Min	Тур	Max	
Chip width	1245	1260	1275	
Chip length	1098.6	1113.6	1128.6	
Chip thickness	105	120	135	
Bond pad width	-	95	-	

Unit: µm

Note: 1. Allowable abnormal aperture is 1%.

2. Continuous abnormal aperture (x, y or diagonal direction) is not allowed.

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